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FEATURES

Avalanche Rugged Technology

Rugged Gate Oxide Technology

Lower Input Capacitance

Improved Gate Charge

Extended Safe Operating Area

• Lower Leakage Current : 10 μ A (Max.) @ $V_{DS} = -60V$

• Lower $R_{DS(ON)}$: 0.206 Ω (Typ.)

 $BV_{DSS} = -60 V$

 $R_{DS(on)} = 0.28 \Omega$

 $I_D = -7.8 \text{ A}$

D-PAK

I-PAK





1. Gate 2. Drain 3. Source

Absolute Maximum Ratings

Symbol	Characteristic	Value	Units
V_{DSS}	Drain-to-Source Voltage	-60	V
	Continuous Drain Current (T _C =25°C)	-7.8	^
l _D	Continuous Drain Current (T _C =100°C)	-5.5	Α
I _{DM}	Drain Current-Pulsed ①	31	Α
V_{GS}	Gate-to-Source Voltage	±30	V
E _{AS}	Single Pulsed Avalanche Energy ②	155	mJ
I _{AR}	Avalanche Current ①	-7.8	Α
E_AR	Repetitive Avalanche Energy	3.2	mJ
dv/dt	Peak Diode Recovery dv/dt	-5.5	V/ns
	Total Power Dissipation (T _A =25°C) *	2.5	W
P_{D}	Total Power Dissipation (T _C =25°C)	32	W
	Linear Derating Factor	0.26	W/°C
т т	Operating Junction and	FF to 1450	
T_J , T_STG	Storage Temperature Range	- 55 to +150	°C
_	Maximum Lead Temp. for Soldering	200	
T _L	Purposes, 1/8" from case for 5-seconds	300	

Thermal Resistance

Symbol	Characteristic	Тур.	Max.	Units
$R_{ heta JC}$	Junction-to-Case		3.91	
$R_{ heta JA}$			50	°C/W
$R_{ heta JA}$			110	

^{*} When mounted on the minimum pad size recommended (PCB Mount).



Electrical Characteristics (T_C=25°C unless otherwise specified)

Symbol	Characteristic	Min.	Тур.	Max.	Units	Test Condition
BV _{DSS}	Drain-Source Breakdown Voltage	-60			٧	V _{GS} =0V,I _D =-250μA
$\Delta \text{BV}/\Delta \text{T}_{\text{J}}$	Breakdown Voltage Temp. Coeff.		-0.04		V/°C	I _D =-250μA See Fig 7
$V_{GS(th)}$	Gate Threshold Voltage	-2.0		-4.0	V	V_{DS} =-5V, I_{D} =-250 μ A
	Gate-Source Leakage, Forward			-100	nA	V _{GS} =-20V
I _{GSS}	Gate-Source Leakage, Reverse			100	ПА	V _{GS} =20V
	Drain to Course Leekens Current			-10		V _{DS} =-60V
I _{DSS}	Drain-to-Source Leakage Current			-100	μΑ	V_{DS} =-48V, T_{C} =125 $^{\circ}$ C
_	Static Drain-Source					\\ 40\\ 0.00
R _{DS(on)}	On-State Resistance			0.28	Ω	V_{GS} =-10V, I_{D} =-3.9A 4
g _{fs}	Forward Transconductance		3.7		S	V _{DS} =-30V,I _D =-3.9A ④
C _{iss}	Input Capacitance		465	600		\\
C _{oss}	Output Capacitance		140	215	рF	$V_{GS}=0V, V_{DS}=-25V, f=1MHz$
C _{rss}	Reverse Transfer Capacitance		40	60		See Fig 5
t _{d(on)}	Turn-On Delay Time		11	30		V 20VI 0.7A
t _r	Rise Time Turn-Off Delay Time		21	50	ns	V_{DD} =-30V, I_{D} =-9.7A,
t _{d(off)}			29	65		$R_G=18 \Omega$
t _f	Fall Time		20	50		See Fig 13 46
Q_g	Total Gate Charge		15	19		V _{DS} =-48V,V _{GS} =-10V,
Q_{gs}	Gate-Source Charge		2.9		nC	I _D =-9.7A
Q_{gd}	Gate-Drain("Miller") Charge		6.0			See Fig 6 & Fig 12 45

Source-Drain Diode Ratings and Characteristics

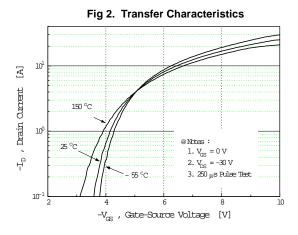
Symbol	Characteristic		Тур.	Max.	Units	Test Condition
Is	Continuous Source Current			-7.8	_	Integral reverse pn-diode
I _{SM}	Pulsed-Source Current ①			-31	А	in the MOSFET
V_{SD}	Diode Forward Voltage			-3.8	٧	$T_J = 25^{\circ}C, I_S = -7.8A, V_{GS} = 0V$
t _{rr}	Reverse Recovery Time		80		ns	$T_J = 25^{\circ}C, I_F = -9.7A$
Q_{rr}	Reverse Recovery Charge		0.22		μС	di _F /dt=100A/μs

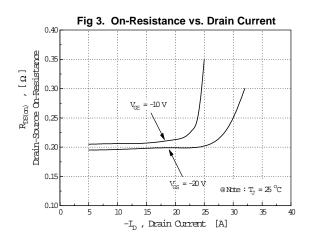
Notes;

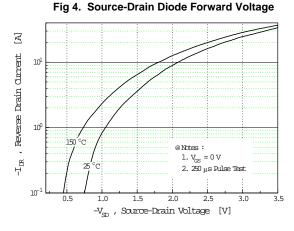
1 Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature

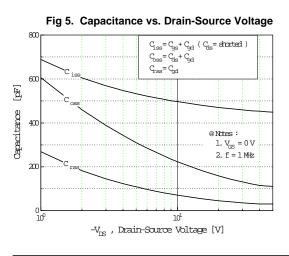
② L=3.0mH, I_{AS} =-7.8A, V_{DD} =-25V, R_{G} =27 Ω^* , Starting T_{J} =25°C ③ I_{SD} <-9.7A, di/dt \leq 250A/ μ s, V_{DD} < BV_{DSS}, Starting T_{J} =25°C ④ Pulse Test: Pulse Width = 250 μ s, Duty Cycle \leq 2%

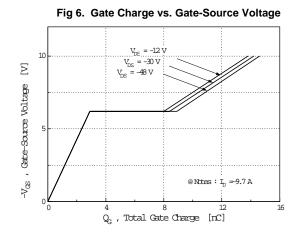
5 Essentially Independent of Operating Temperature

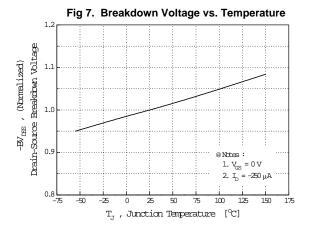


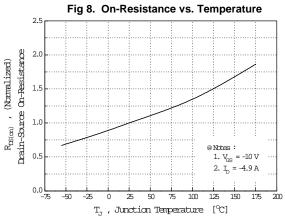












Question in This Area
is Limited by R DS(cm)

10

10

0.1 ms

10 ms

10

10 ms

10

2. T₀ = 25 °C

2. T₀ = 150 °C

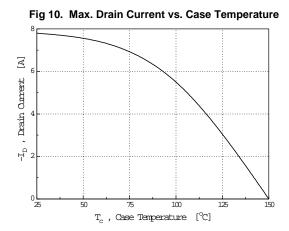
3. Single Pulse

 $^{10^{\mathrm{l}}}$ -V_{DS} , Drain-Source Voltage [V]

10-1

10⁰

Fig 9. Max. Safe Operating Area



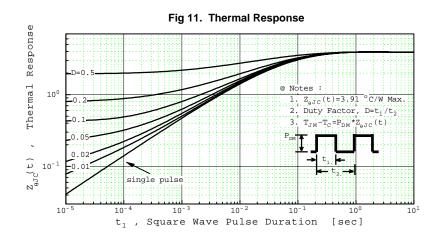


Fig 12. Gate Charge Test Circuit & Waveform

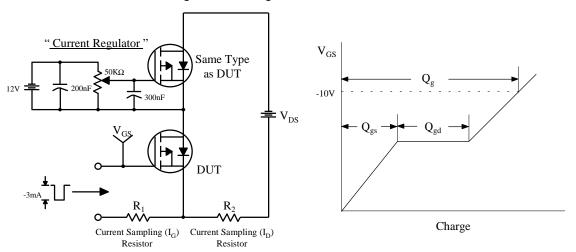


Fig 13. Resistive Switching Test Circuit & Waveforms

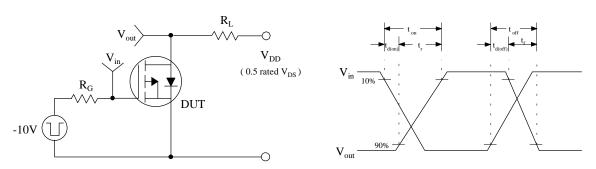


Fig 14. Unclamped Inductive Switching Test Circuit & Waveforms

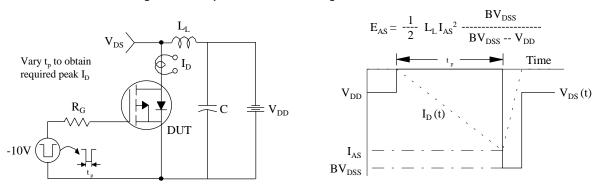
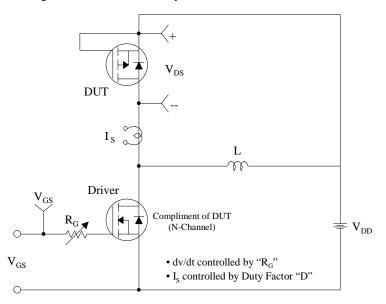
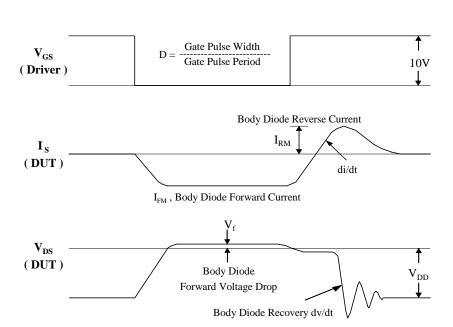


Fig 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms





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Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
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